

DMTH6010LPSQ

60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on)	I₀ Tc = +25°C (Note 9)
60V	8mΩ @ V _{GS} = 10V	100A
000	12mΩ @ V _{GS} = 4.5V	85A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine management systems
- Body control electronics
- DC-DC converters

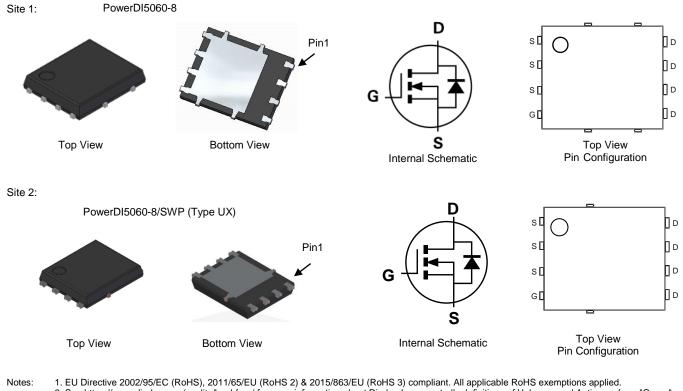
Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH6010LPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (63)
- Weight: 0.097 grams (Approximate)



EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

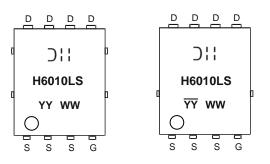


Ordering Information (Note 4)

Part Number	Packago	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMTH6010LPSQ-13	PowerDI5060-8	2,500	Tape & Reel	
DMTH6010LPSQ-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

Note: 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



D: : =Manufacturer's Marking H6010LS = Product Type Marking Code YYWW = Date Code Marking YY or YY = Last Two Digits of Year (ex: 23 = 2023) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	60	V	
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current (Note 5)	T _A = +25°C T _A = +70°C	lo	13.5 10.4	A
Continuous Drain Current (Notes 6 & 9)	Tc = +25°C Tc = +100°C	lo	100 75	A
Maximum Continuous Body Diode Forward Current (Note 6)		ls	100	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		ldм	400	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		I _{SM}	400	A
Avalanche Current, L=0.1mH		las	20	A
Avalanche Energy, L=0.1mH		Eas	20	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)		R _{0JA}	57	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	PD	136	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.1	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	Cymber		• 76	max	•	
Drain-Source Breakdown Voltage	BV _{DSS}	60	—	—	V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS		_	1	μA	$V_{DS} = 48V, V_{GS} = 0V$
Gate-Source Leakage	lgss			±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)	·					·
Gate Threshold Voltage	Vgs(th)	1	_	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Descent		6.4	8	mΩ	$V_{GS} = 10V, I_D = 20A$
Static Drain-Source On-Resistance	RDS(ON)		8.3	12	11152	V _{GS} = 4.5V, I _D = 20A
Diode Forward Voltage	Vsd	_	0.8	1.2	V	$V_{GS} = 0V$, $I_{S} = 20A$
DYNAMIC CHARACTERISTICS (Note 8)	·					*
Input Capacitance	Ciss		2,090	_		
Output Capacitance	Coss		746	_	pF	$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz
Reverse Transfer Capacitance	Crss		38.5	—		
Gate Resistance	Rg	0.2	0.59	1.5	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	19.3	—		
Total Gate Charge (V _{GS} = 10V)	Qg	_	41.3	—	nC	N 2014 L 2014
Gate-Source Charge	Qgs		6	_	nc	$V_{DS} = 30V, I_D = 20A$
Gate-Drain Charge	Qgd	_	8.8	—		
Turn-On Delay Time	t _{D(ON)}	_	5.7	_		
Turn-On Rise Time	tR	_	4.3	—	ns	$V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 20A, R_G = 3\Omega$
Turn-Off Delay Time	tD(OFF)	_	23.4	_		
Turn-Off Fall Time	tF	_	9.7	—	1	
Body Diode Reverse Recovery Time	t _{RR}		35.4	_	ns	
Body Diode Reverse Recovery Charge	Qrr		38.2	_	nC	IF = 20A, di/dt = 100A/µs

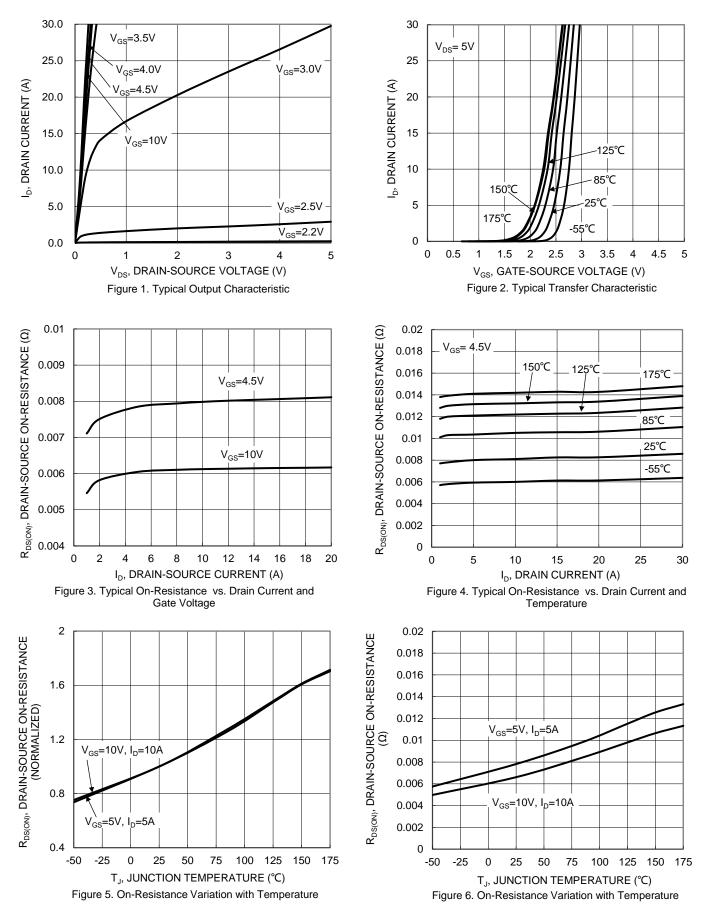
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.
Limited by package.



DMTH6010LPSQ





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V_{GS}=0V, T_J=85°C

V_{GS}=0V, T_J=25°C

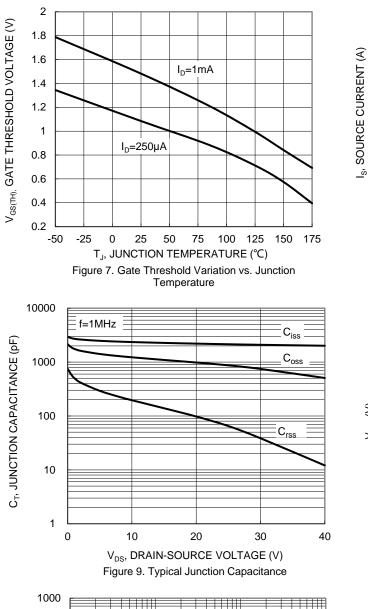
V_{GS}=0V, <u>T</u>J=-55°C

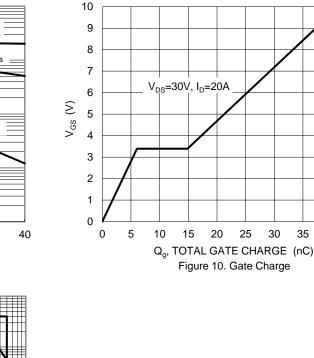
1.2

40

45

1.5





30

25

20

15

10

5

0

0

V_{GS}=0V, T_J=125

V_{GS}=0V, T_J=150°C

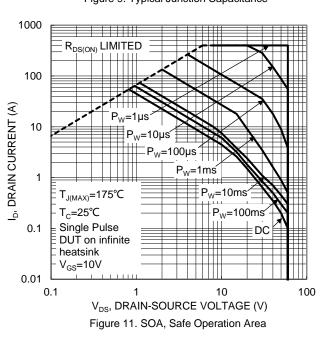
V_{GS}=0V, TJ=175℃

0.3

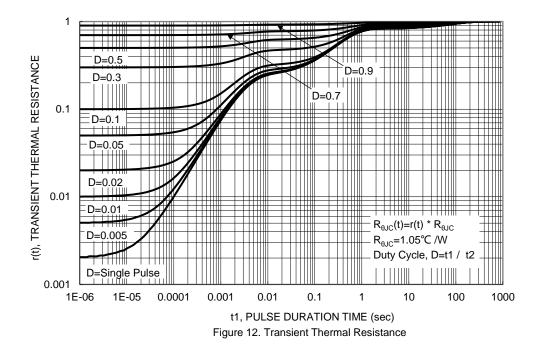
0.6

0.9

V_{SD}, SOURCE-DRAIN VOLTAGE (V) Figure 8. Diode Forward Voltage vs. Current





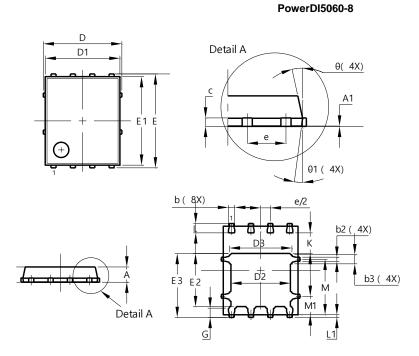




Package Outline Dimensions

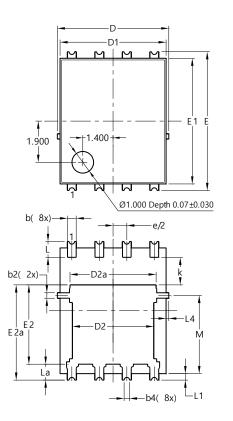
Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

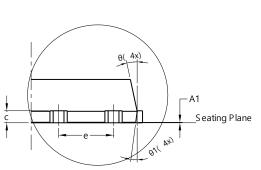


PowerDI5060-8						
Dim						
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D	Ļ	5.15 BSC				
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
Е	(6.15 BSC				
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е		1.27 BSC				
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
Μ	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
Θ1	6°	8°	7°			
All						

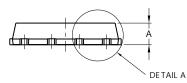
Site 2:



PowerDI5060-8/SWP (Type UX)



DETAIL A



PowerDI5060-8/SWP					
	(Type UX)				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	().25REF			
С	0.230	0.330	0.277		
D	5	.15 BS0	0		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
E	6.40 BSC				
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1	.27BSC)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	0	.050RE	F		
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	All Dimensions in mm				

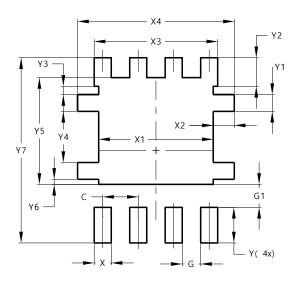


Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

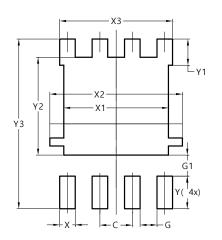
PowerDI5060-8



Dimensions	Value (in mm)
	· · · · ·
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)	
С	1.270	
G	0.660	
G1	0.820	
Х	0.610	
X1	4.100	
X2	5.190	
X3	4.420	
Y	1.270	
Y1	1.020	
Y2	3.810	
Y3	6.610	



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